

50 MHz to 850 MHz, CASCADABLE ACTIVE BIAS InGaP HBT MMIC AMPLIFIER





Product Description

RFMD's SBB2089Z is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB2089Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB2089Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50Ω .



Features

- OIP₃=42.8dBm at 240MHz
- P_{1dB}=20.8dBm at 500MHz
- Single Fixed 5V Supply
- Robust 2000V ESD, Class 2
- Patented Thermal Design and Bias Circuit
- Low Thermal Resistance

Applications

- Receiver IF Amplifier
- Cellular, PCS, GSM, UMTS
- Wireless Data, Satellite Terminals

| | Specification | | l lusit | Condition | |
|------|--|---|--|--|--|
| Min. | Тур. | Max. | Unit | Condition | |
| | 20.0 | | dB | 70MHz | |
| 18.5 | 20.0 | 21.5 | dB | 240 MHz | |
| 18.5 | 20.0 | 21.5 | dB | 400MHz | |
| | 20.0 | | dBm | 70MHz | |
| | 20.0 | | dBm | 240 MHz | |
| 18.5 | 21.0 | | dBm | 400MHz | |
| | 41.0 | | dBm | 70MHz | |
| | 43.0 | | dBm | 240 MHz | |
| 39.0 | 41.0 | | dBm | 400 MHz | |
| | 50 to 850 | | MHz | Minimum 10dB | |
| 15.0 | 20.0 | | dB | 70MHz to 5000MHz | |
| 11.0 | 14.0 | | dB | 70MHz to 5000MHz | |
| | 2.7 | 3.7 | dB | 500MHz | |
| | 22.0 | | dB | 70MHz to 5000MHz | |
| | 48.8 | | °C/W | junction - lead | |
| | 5.0 | 5.3 | V | | |
| 82.0 | 90.0 | 98.0 | mA | | |
| | 18.5 18.5 18.5 39.0 15.0 11.0 | Min. Typ. 20.0 18.5 20.0 18.5 20.0 20.0 18.5 20.0 20.0 20.0 20.0 20.0 18.5 21.0 41.0 43.0 39.0 41.0 50 to 850 15.0 20.0 11.0 14.0 2.7 22.0 48.8 5.0 | Min. Typ. Max. 20.0 20.0 18.5 20.0 21.5 18.5 20.0 21.5 20.0 20.0 20.0 20.0 20.0 20.0 18.5 21.0 20.0 18.5 21.0 20.0 18.5 21.0 20.0 18.5 21.0 20.0 15.0 20.0 20.0 11.0 14.0 2.7 22.0 22.0 48.8 5.0 5.3 | Min. Typ. Max. Unit 20.0 dB 18.5 20.0 21.5 dB 18.5 20.0 21.5 dB 18.5 20.0 21.5 dB 20.0 dBm 20.0 dBm 20.0 dBm 3Bm 3Bm 18.5 21.0 dBm 3Bm 18.5 21.0 dBm 3Bm 18.5 21.0 dBm 3Bm 18.5 21.0 dBm 3Bm 15.0 20.0 dBm 3Bm 15.0 20.0 dB 3B 11.0 14.0 dB 3C 22.0 dB 48.8 °C/W 5.0 5.3 V | |

Test Conditions: $V_D = 5V$, $I_D = 90$ mA Typ., OIP₃ Tone Spacing = 1 MHz, P_{OUT} per tone = 0 dBm, $T_L = 25^{\circ}$ C, $Z_S = Z_L = 50\Omega$, Tested with Bias Tees

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Absolute Maximum Ratings

| ¥ | | |
|--|------------|------|
| Parameter | Rating | Unit |
| Device Current (I _D) | 110 | mA |
| Device Voltage (V _D) | 5.5 | V |
| RF Input Power | 24 | dBm |
| Junction Temp (T _J) | +150 | °C |
| Operating Temp Range (T_L) | -40 to +85 | °C |
| Storage Temp | +150 | °C |
| Power Dissipation | 0.61 | W |
| ESD Rating - Human Body Model (HBM) | Class 2 | |
| Moisture Sensitivity Level | MSL2 | |

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L)/R_{TH}$, j-l and $T_L = T_{LEAD}$

Typical RF Performance at Key Operating Frequencies (With Application Circuit)

| Caution! | ESE |
|----------|-----|

D sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

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| pical RF Periormance at Rey Operating Frequencies (with Application Circuit) | | | | | | | | |
|--|------|-------|-------|------|------|------|------|------|
| Parameter | Unit | 50MHz | 70MHz | 100 | 240 | 400 | 500 | 850 |
| | | | | MHz | MHz | MHz | MHz | MHz |
| Small Signal Gain, S ₂₁ | dB | 20.0 | 20.0 | 20.0 | 20.0 | 20.0 | 20.0 | 20.0 |
| Output Third Order Intercept Point, OIP3 | dBm | 40.0 | 40.0 | 41.0 | 42.0 | 41.0 | 40.0 | 35.0 |
| Output Power at 1dB Compression, P_{1dB} | dBm | 20.0 | 20.0 | 20.0 | 20.0 | 20.0 | 20.0 | 19.0 |
| Input Return Loss, IRL | dB | 15.0 | 18.0 | 19.0 | 20.0 | 20.0 | 19.0 | 16.0 |
| Output Return Loss, ORL | dB | 21.0 | 23.0 | 24.0 | 27.0 | 34.0 | 30.0 | 14.0 |
| Reverse Isolation, S ₁₂ | dB | 22.0 | 22.0 | 22.0 | 22.0 | 22.0 | 22.0 | 22.0 |
| Noise Figure, NF | dB | 3.1 | 2.9 | 2.7 | 2.6 | 2.7 | 2.8 | 2.9 |

Test Conditions: $V_{CC}=5V$ I_D=90mA Typ. OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=0dBm T_L=25°C Z_S=Z_L=50 Ω

Data on charts taken with Application Circuit

Noise Figure versus Frequency







50.0 150.0 250.0 350.0 450.0 550.0 650.0 750.0 850.0 Frequency (MHz)

25C

400 85C





Application Circuit S-Parameters Over Temperature







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S-Parameters Over Temperature (Bias Tee) S11 versus Frequency

S21 versus Frequency



Device Current Over Temperature with Application Circuit





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| Pin | Function | Description |
|------|-------------|--|
| 1 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 2, 4 | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 3 | RF OUT/BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper- ation. |

Suggested PCB Pad Layout



Package Drawing

Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.











Package Marking



Ordering Information

| Ordering Code | Description |
|---------------|--|
| SBB2089Z | 7" Reel with 1000 pieces |
| SBB2089ZSQ | Sample bag with 25 pieces |
| SBB2089ZSR | 7" Reel with 100 pieces |
| SBB2089ZPCK1 | 50MHz to 850MHz PCBA with 5-piece sample bag |